

WIDE BAND 3-INPUT 1-OUTPUT 3-CIRCUIT VIDEO AMPLIFIER

■GENERAL DESCRIPTION

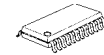
The **NJM2585** is a wide band 3-input 1-output 3-circuit video amplifier. It is suitable for Y, Pb, and Pr signal because frequency range is 50MHz.

The **NJM2585** is suitable for AV receiver, STB, and other high quality AV systems.

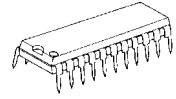
■ FEATURES

- Operating Voltage 4.5 to 9.0V
- Wide frequency range 0dB at 50MHz typ.
- Internal 3 input-1output 3-circuit video switch
- Internal 6dB Amplifier
- Internal 75Ω Driver Circuit
- Power Save Circuit
- Bipolar Technology
- Package Outline DMP24, SDIP22

■PACKAGE OUTLINE

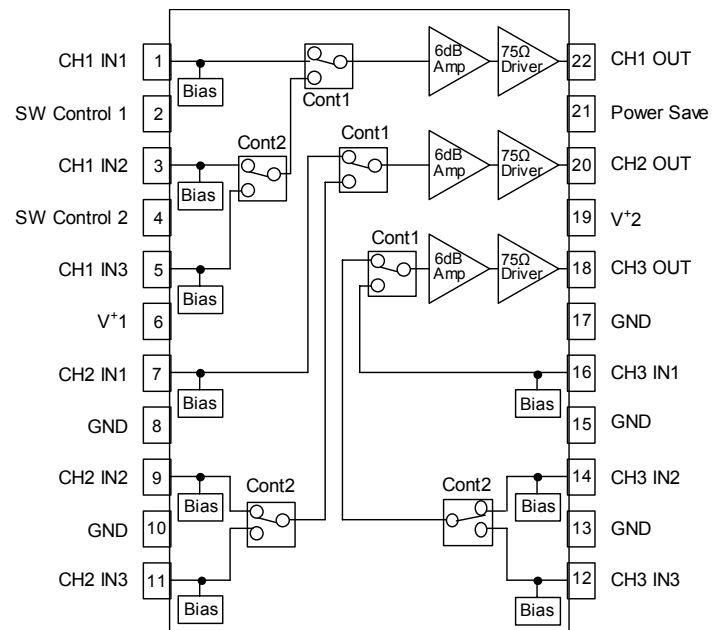
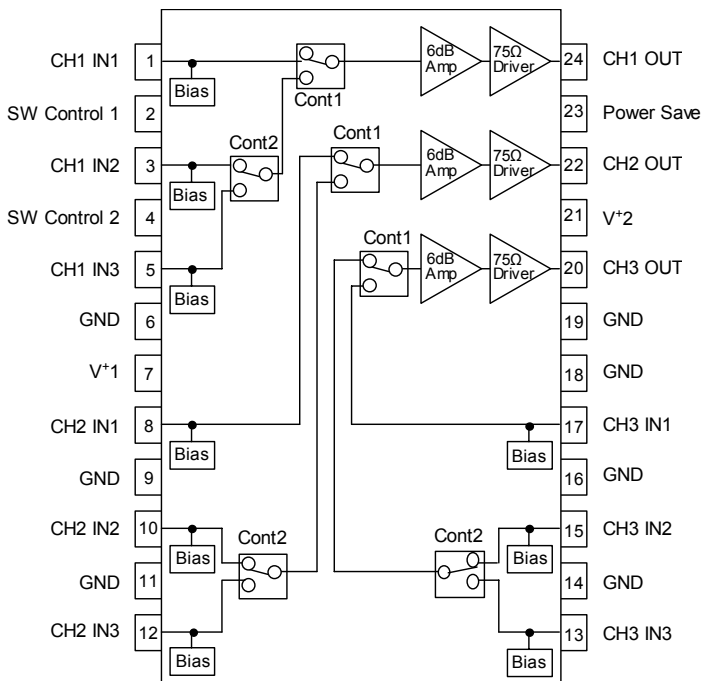


NJM2585M



NJM2585L

■BLOCK DIAGRAM



■ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	12.0	V
Power Dissipation	P _D	500 (DMP24) 700 (SDIP22)	mW
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-40 to +125	°C

■ELECTRICAL CHARACTERISTICS (Ta=25°C, V⁺1=5V, V⁺2=5V, R_L=150Ω)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I _{CC}	No Signal	-	23.0	35.0	mA
Operating Current at Power Save	I _{save}	No Signal, Power Save Mode	-	0.7	1.2	mA
Maximum Output Voltage Swing	V _{om}	V _{in} =100kHz, Sine Signal, THD=1%	2.4	3.0	-	V _{p-p}
Voltage Gain	G _v	V _{in} =1MHz, 1.0V _{p-p} , Sine Signal	5.8	6.2	6.6	dB
Gain Difference Between Channel	ΔG _{vI}	V _{in} =1MHz, 1.0V _{p-p} , Sine Signal (IN1, IN2, IN3)	-0.2	0	+0.2	dB
Gain Difference Between Block	ΔG _{vB}	V _{in} =1MHz, 1.0V _{p-p} , Sine Signal (CH1, CH2, CH3)	-0.2	0	+0.2	dB
Band Width	f		-	50	-	MHz
Frequency Characteristic	G _f	V _{in} =50MHz/1MHz, 1.0V _{p-p} , Sine signal	-	0	-	dB
Channel Cross talk 1	CTI1	V _{in} =4.43MHz, 1.0V _{p-p} , Sine signal	-	-60	-50	dB
Channel Cross talk 2	CTI2	V _{in} =50MHz, 1.0V _{p-p} , Sine signal	-	-40	-	dB
Block Cross talk 1	CTB1	V _{in} =4.43MHz, 1.0V _{p-p} , Sine signal	-	-60	-50	dB
Block Cross talk 2	CTB2	V _{in} =50MHz, 1.0V _{p-p} , Sine signal	-	-40	-	dB
Differential Gain	DG	V _{in} =1.0V _{p-p} , 10step Video Signal	-	0.3	-	%
Differential Phase	DP	V _{in} =1.0V _{p-p} , 10step Video Signal	-	0.3	-	deg
S/N Ratio	SN _v	V _{in} =1.0V _{p-p} , 100kHz to 6MHz 100% White Video Signal	-	65	-	dB
Power Save SW Change Voltage High Level	V _{thPH}	PS	2.0	-	V ⁺	V
Power Save SW Change Voltage Low Level	V _{thPL}	PS	0	-	0.6	V
Input Select SW Change Voltage High Level	V _{thSH}	SW1, SW2	2.0	-	V ⁺	V
Input Select SW Change Voltage Low Level	V _{thSL}	SW1, SW2	0	-	0.6	V

■CONTROL TERMINAL

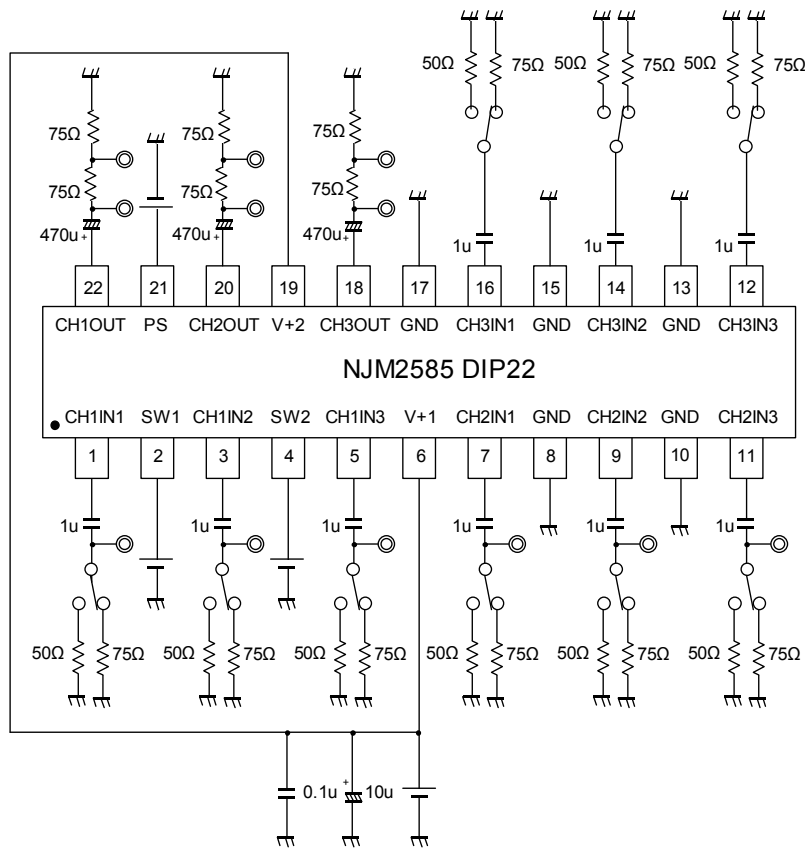
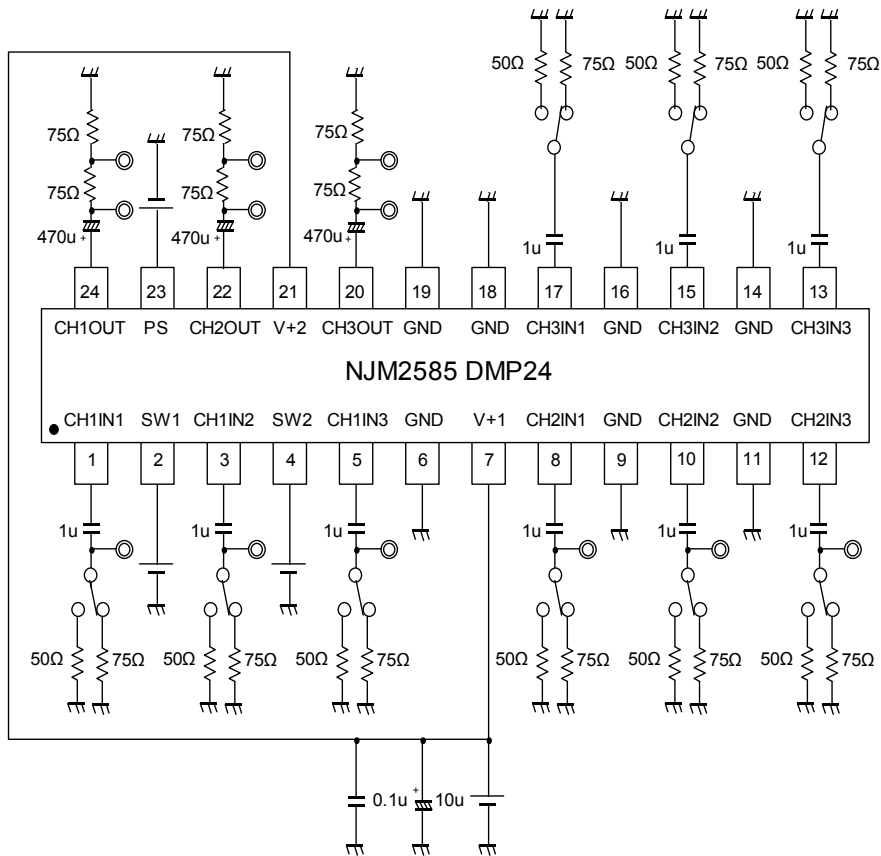
PARAMETER	STATUS	NOTE
Power Save	H	Power Save: OFF
	L	Power Save: ON
	OPEN	Power Save: ON

PARAMETER	STATUS		NOTE
SW Control	SW1	SW2	
	L, OPEN	X	IN1 (X=don't care)
	H	L, OPEN	IN2
	H	H	IN3

■ TERMINAL FUNCTION

PIN NO.	PIN NAME	EQUIVALENT CIRCUIT	DC VOLTAGE (V+=5V)	NOTE
1 3 5 8 10 12 13 15 17	CH1IN1 CH1IN2 CH1IN3 CH2IN1 CH2IN2 CH2IN3 CH3IN1 CH3IN2 CH3IN3		2.5V	
20 22 24	CH3OUT CH2OUT CH1OUT		2.5V	
2 4	SW1 SW2		0V	
23	PowerSave		0V	

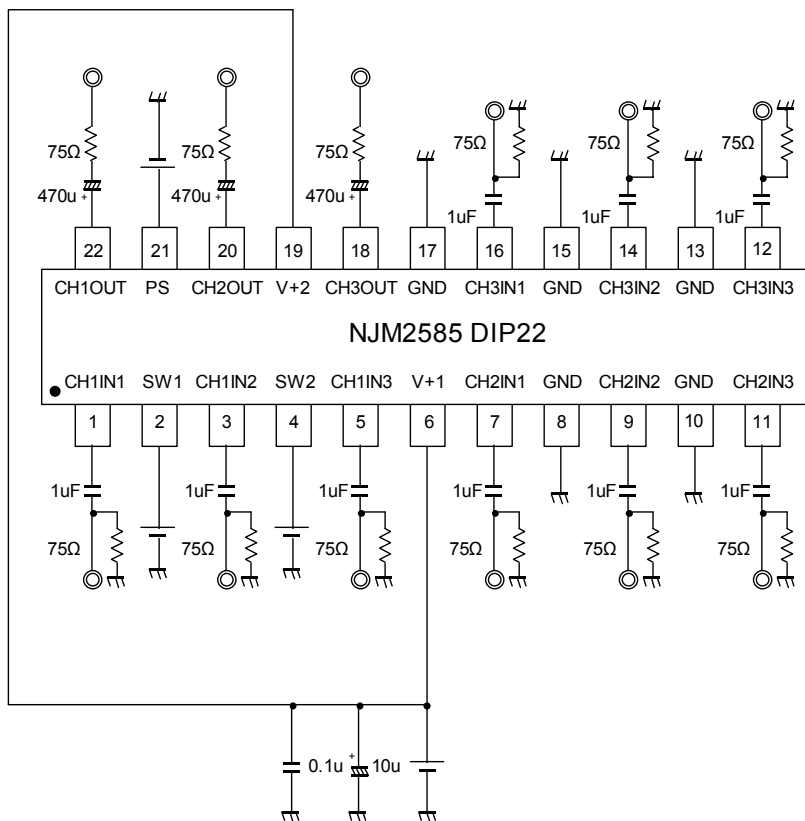
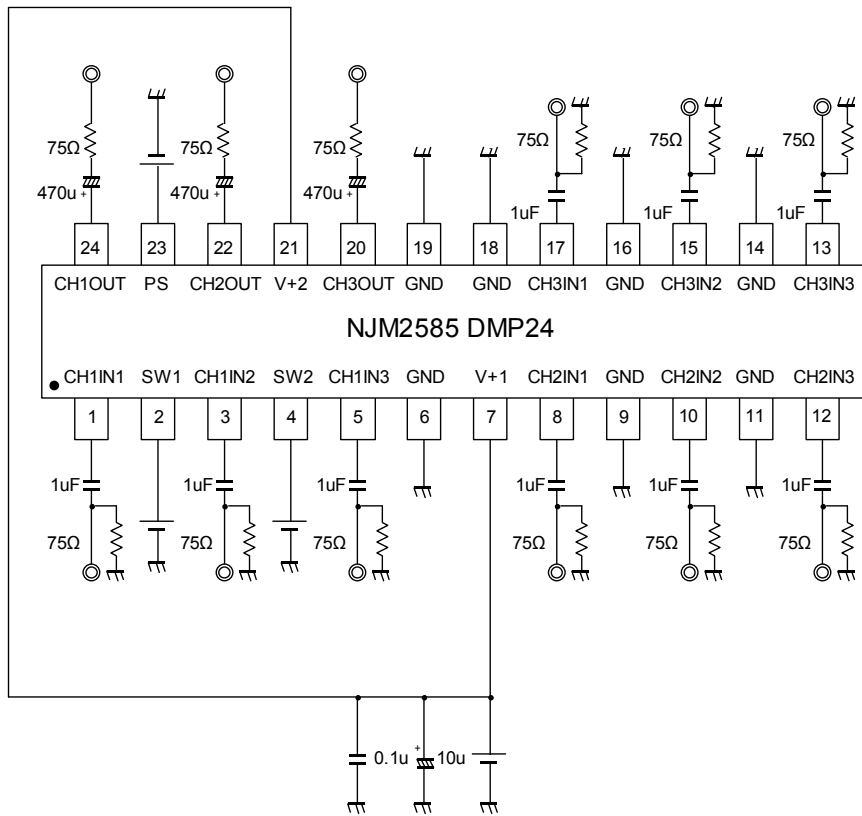
TEST CIRCUIT



NOTE

Please ground all GND terminals.

■APPLICATION CIRCUIT

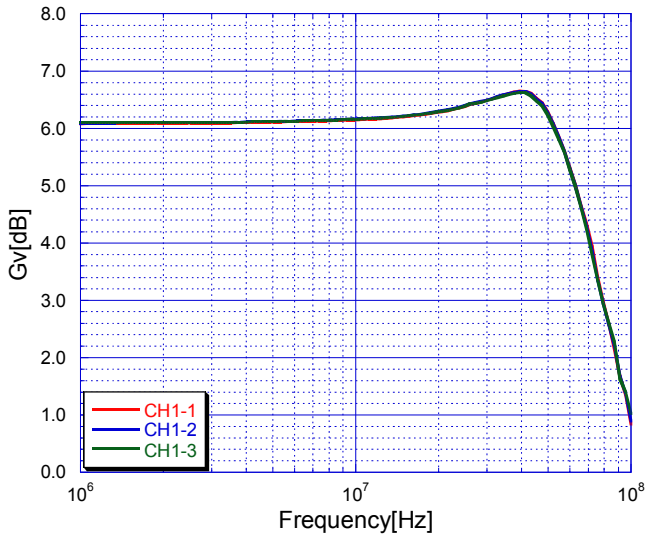


■NOTE

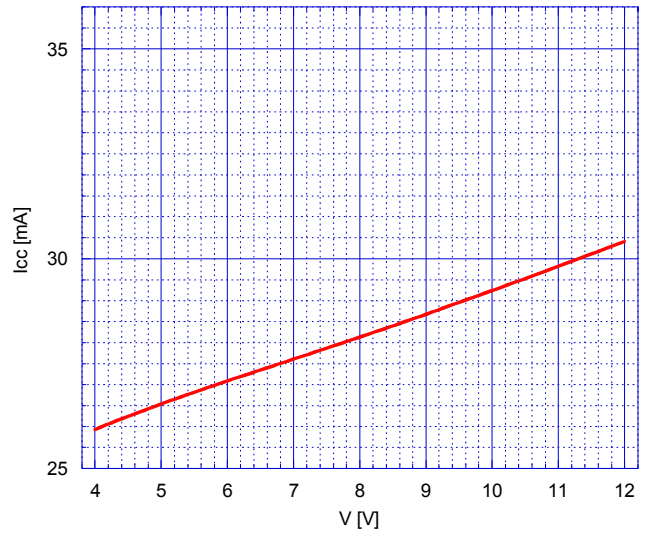
Please ground all GND terminals.

■ TYPICAL CHARACTERISTICS

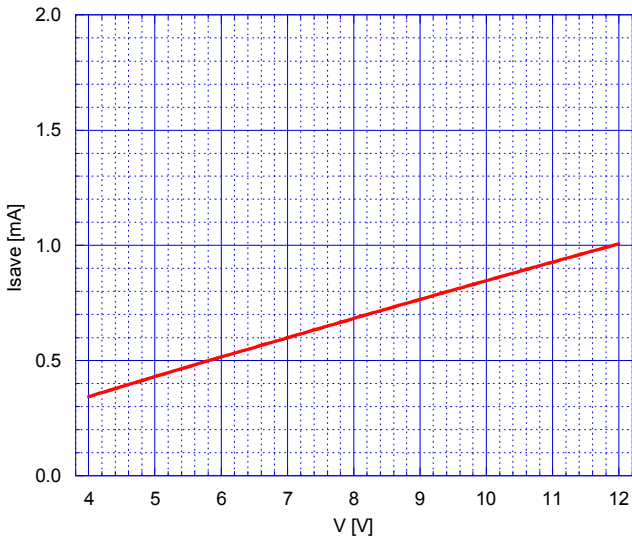
Voltage Gain vs Frequency



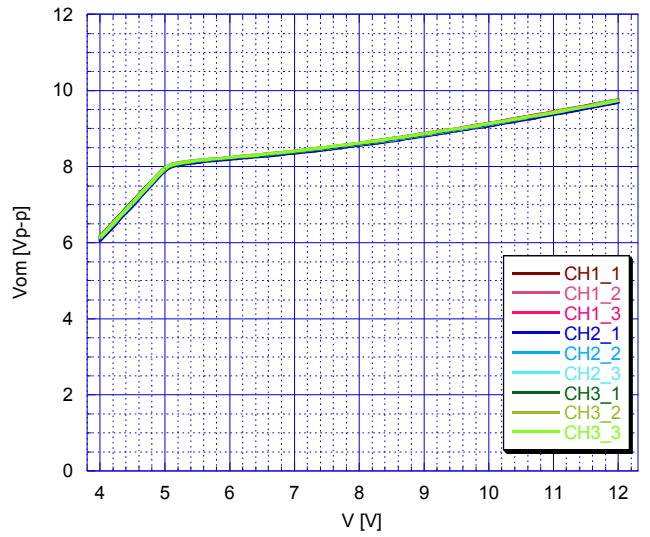
V vs Icc



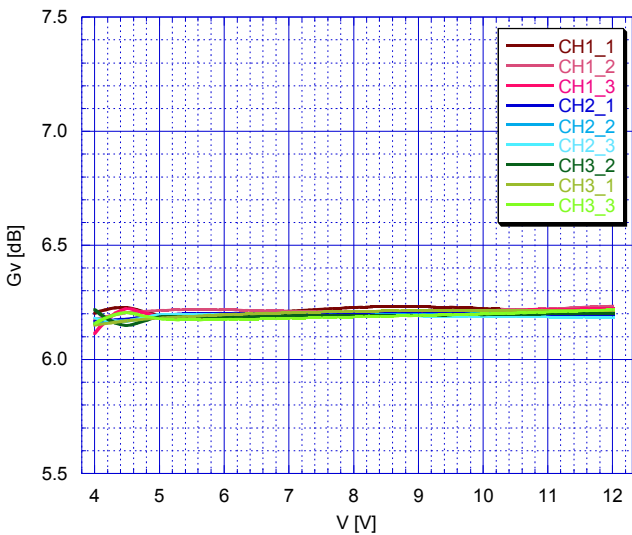
V vs Isave



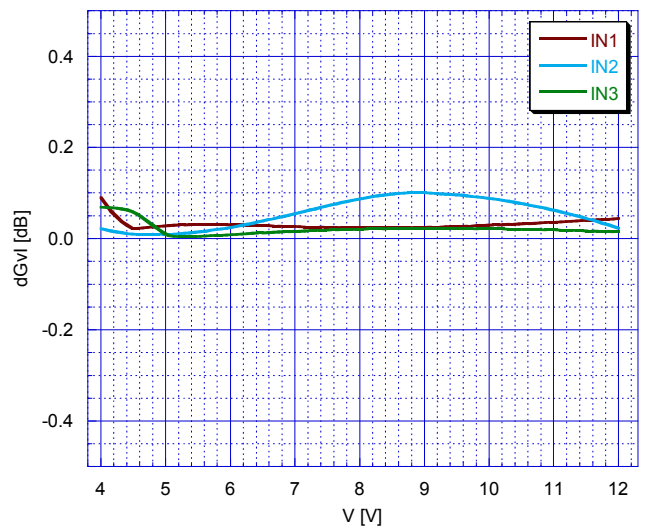
V vs Vom



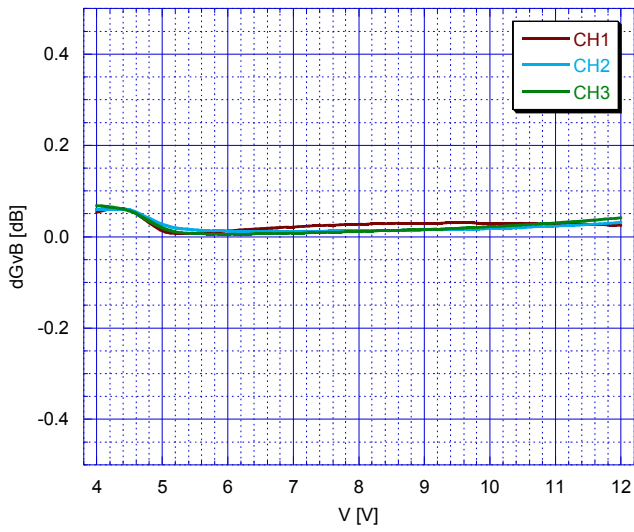
V vs Gv



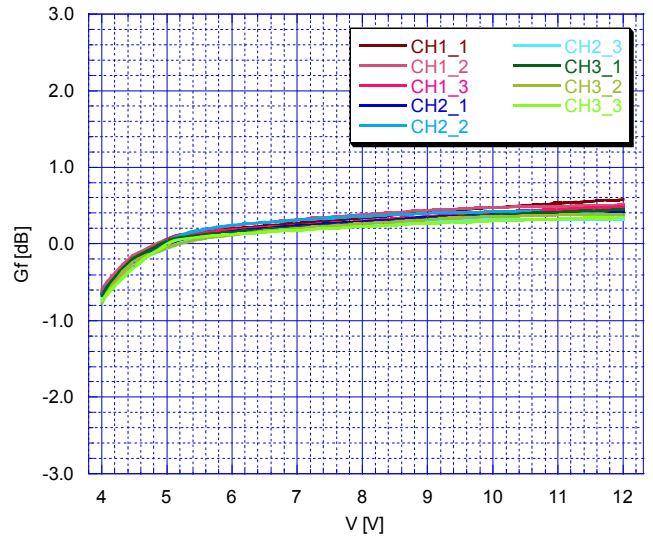
V vs dGv



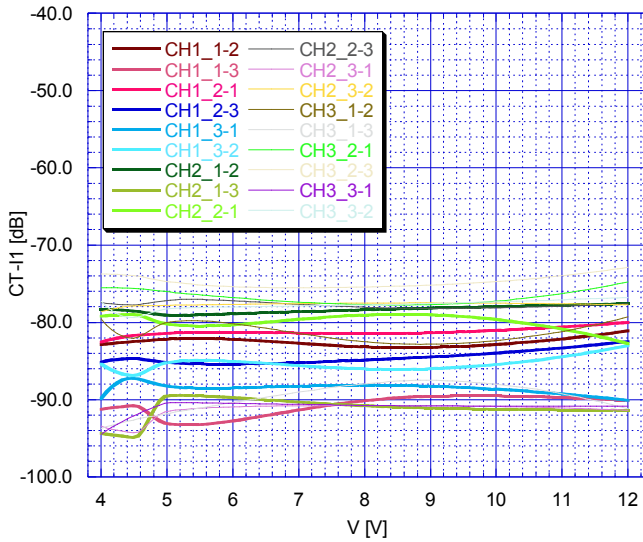
V vs dGvB



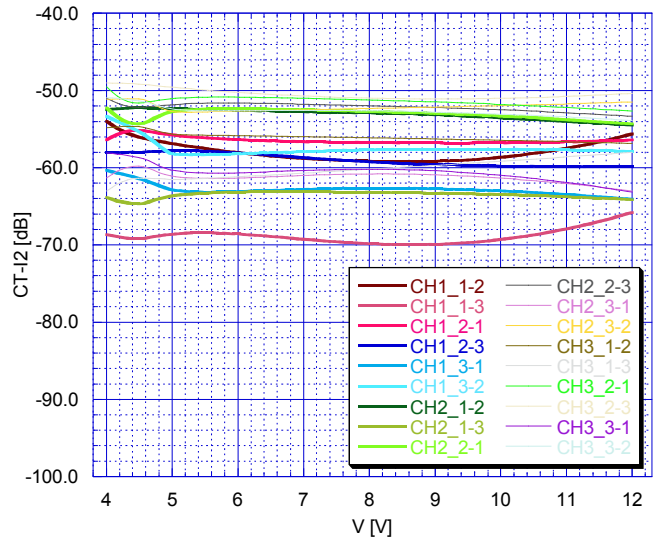
V vs Gf



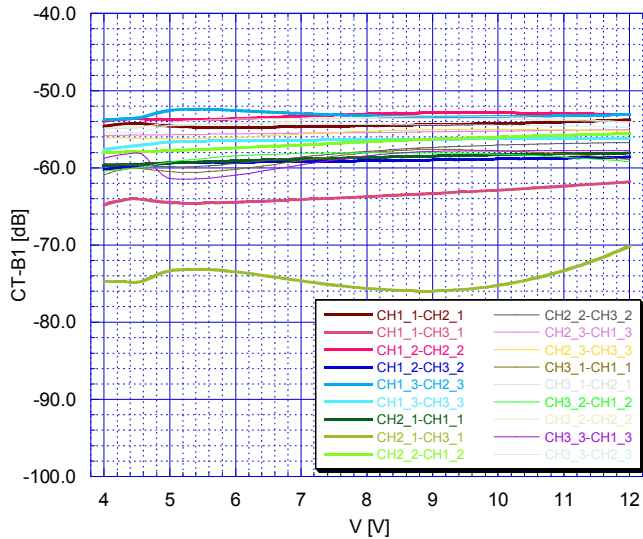
V vs CT- I1



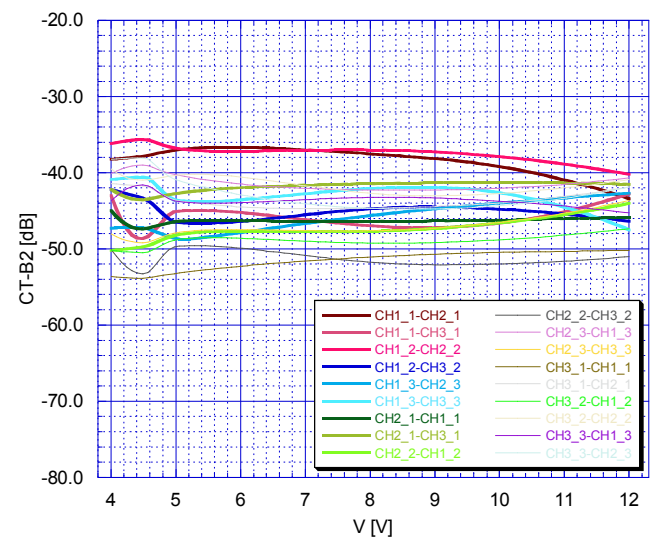
V vs CT- I2



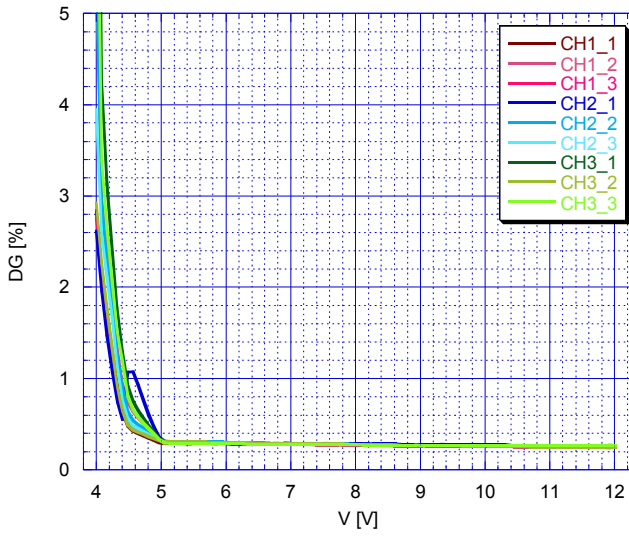
V vs CT- B1



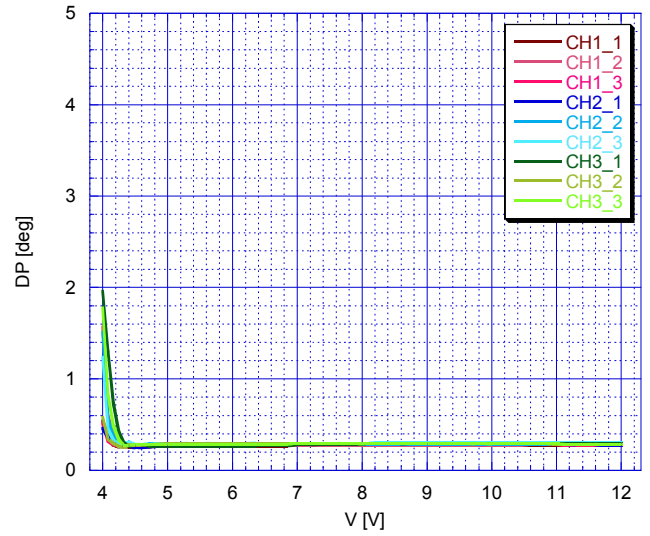
V vs CT- B2



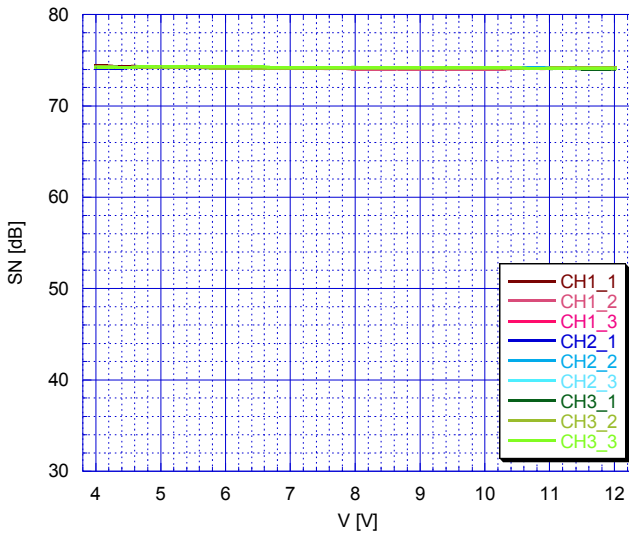
V vs DG



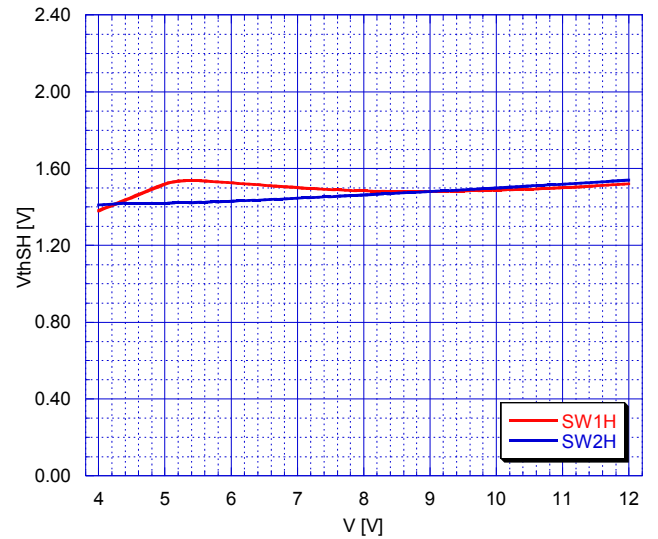
V vs DP



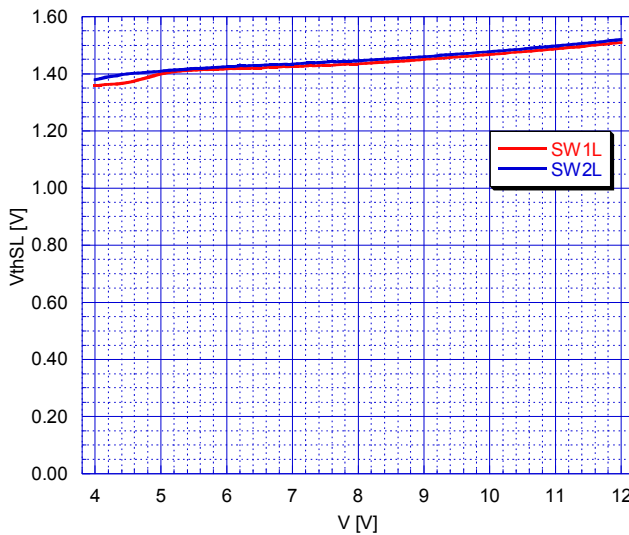
V vs SN



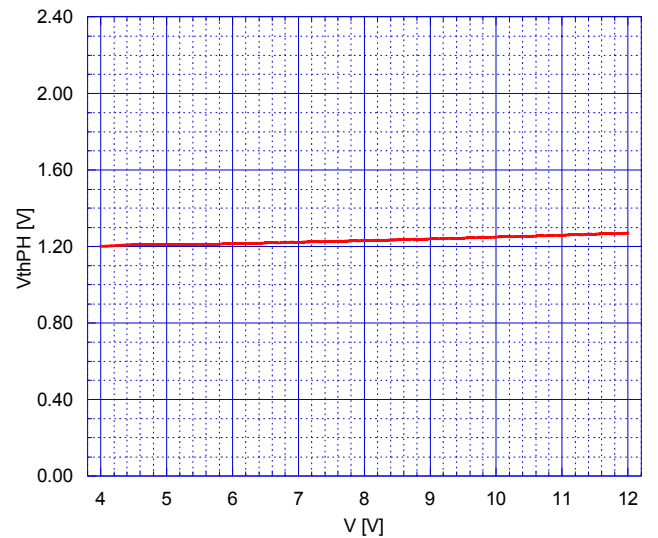
V vs VthSH



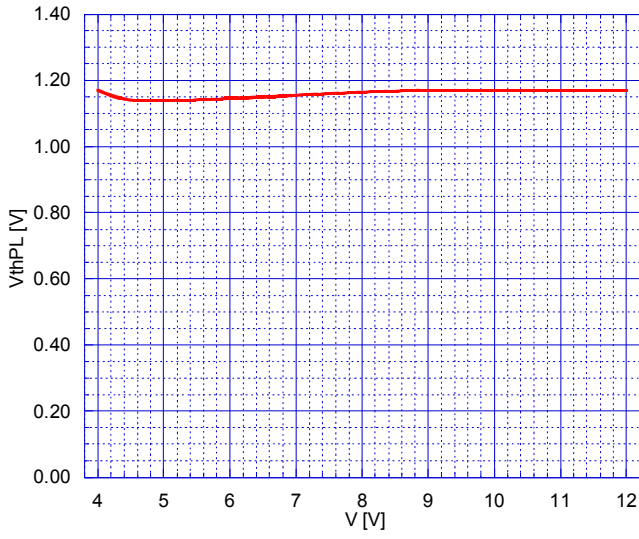
V vs VthSL



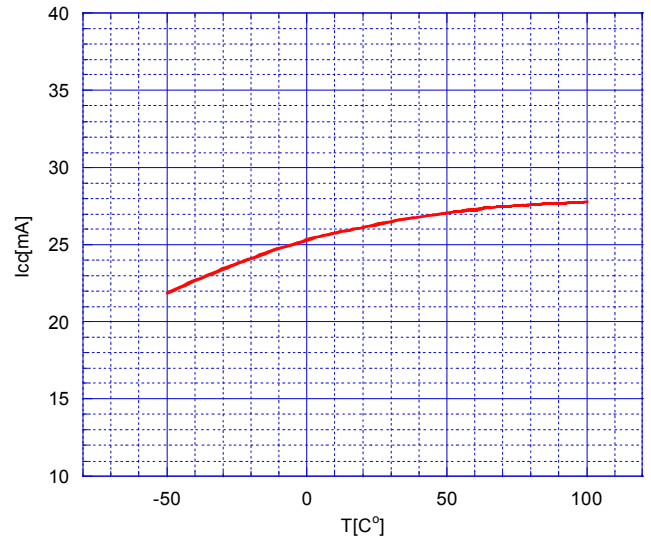
V vs VthPH



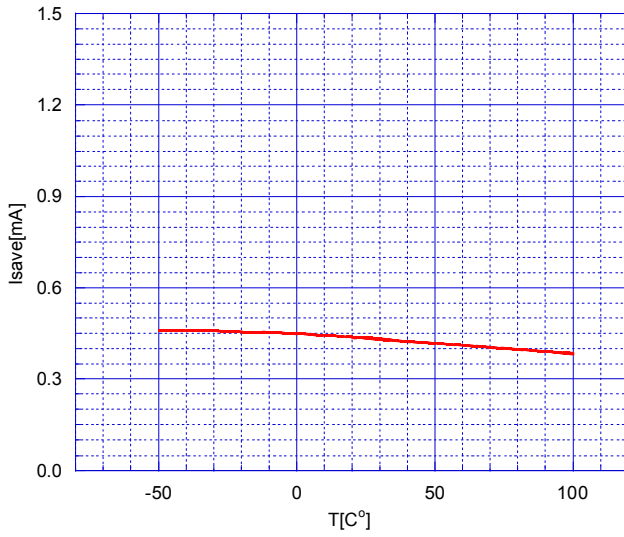
V vs VthPL



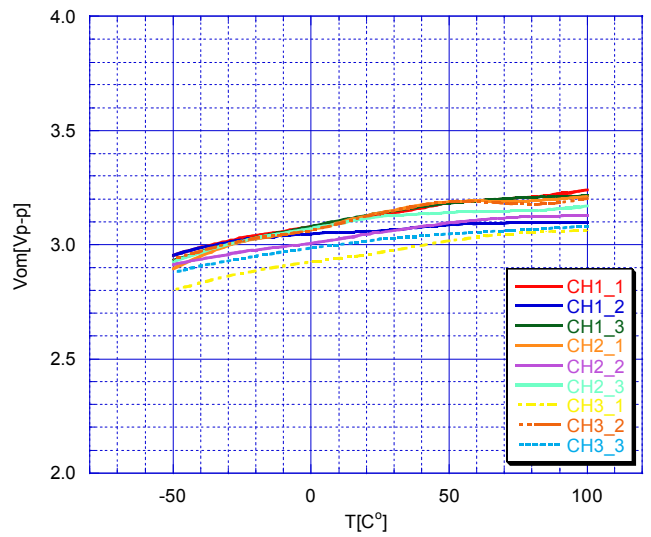
T vs Icc



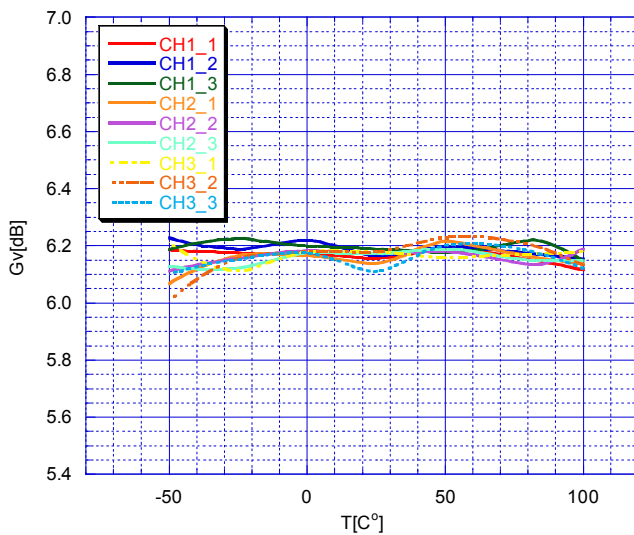
T vs Isave



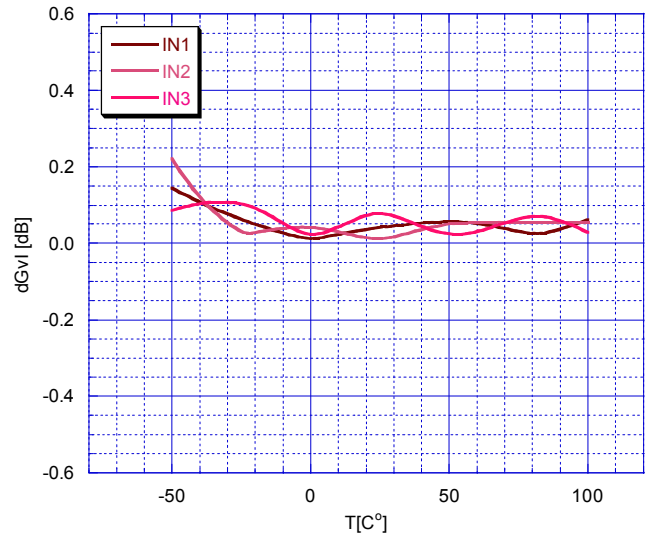
T vs Vom



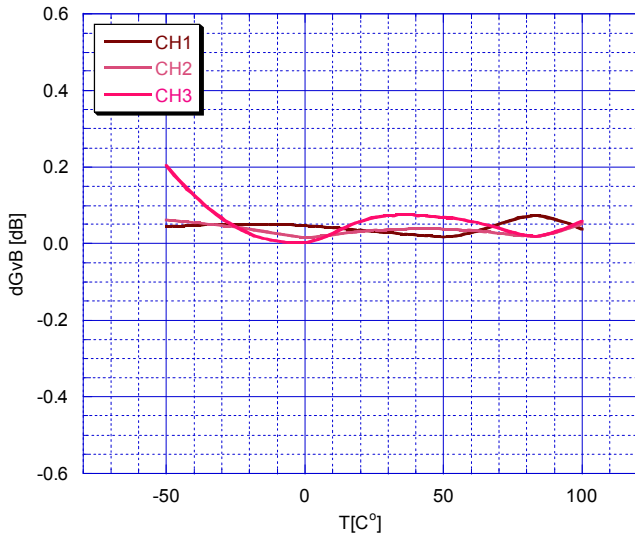
T vs Gv



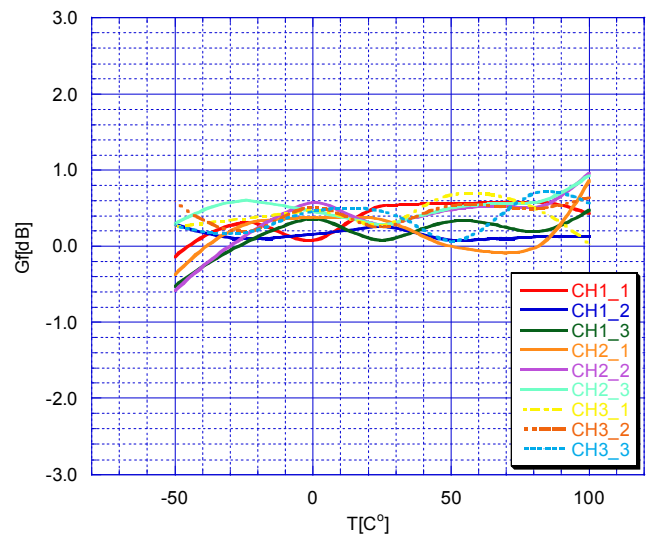
T vs dGvI



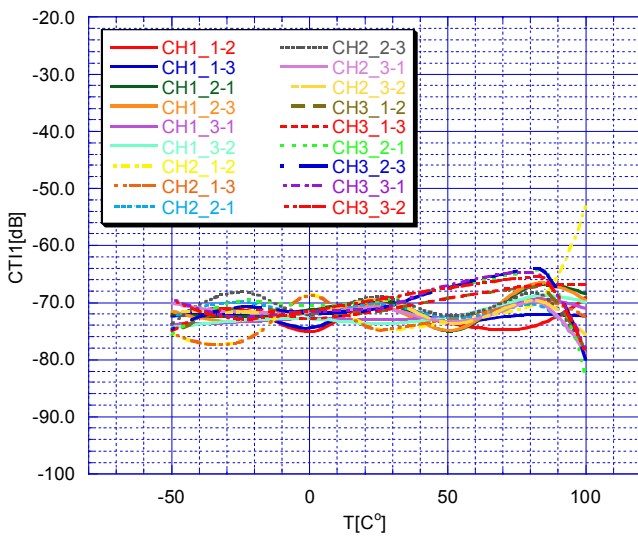
T vs dGvB



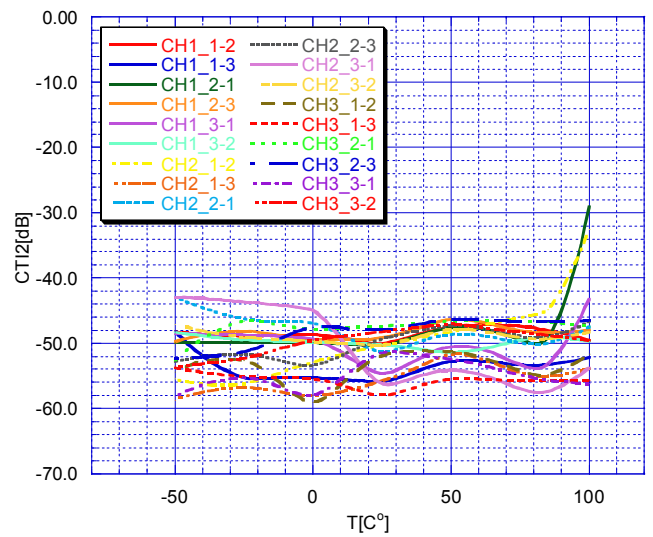
T vs Gf



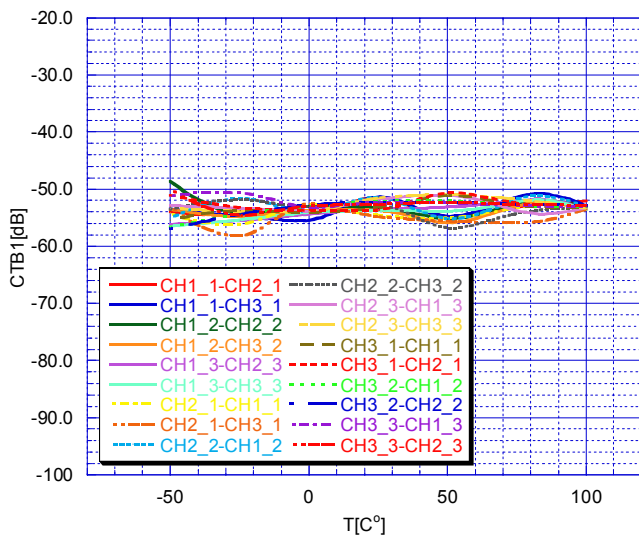
T vs CTI1



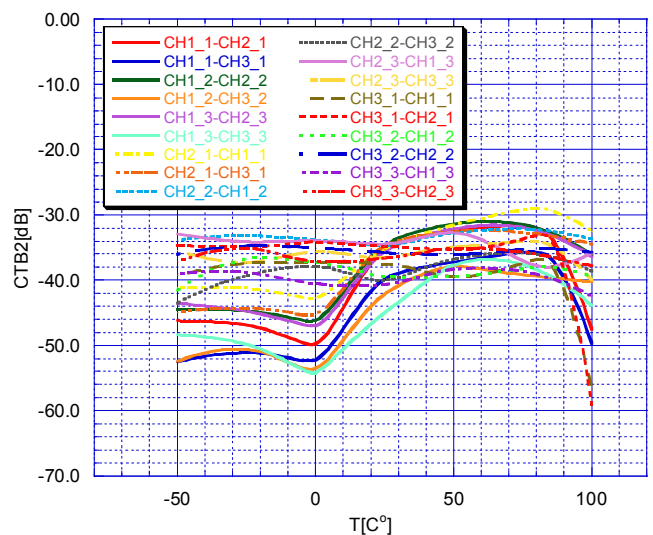
T vs CTI2



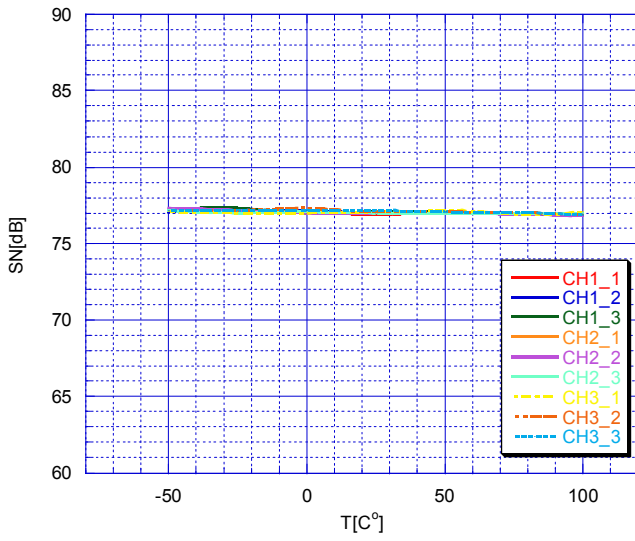
T vs CTB1



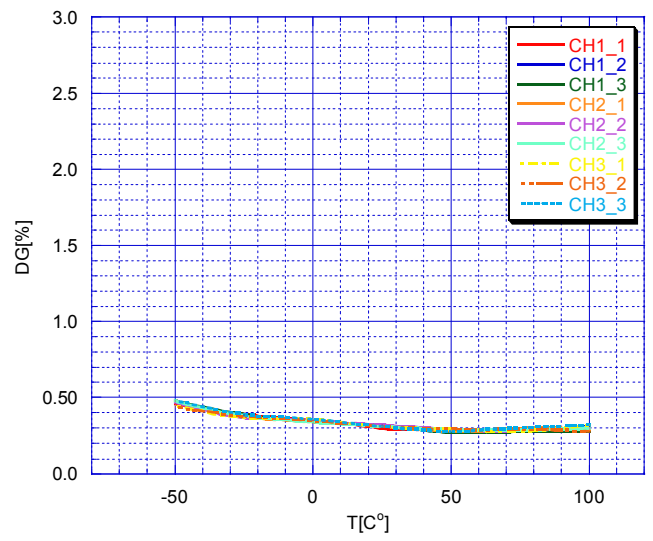
T vs CTB2



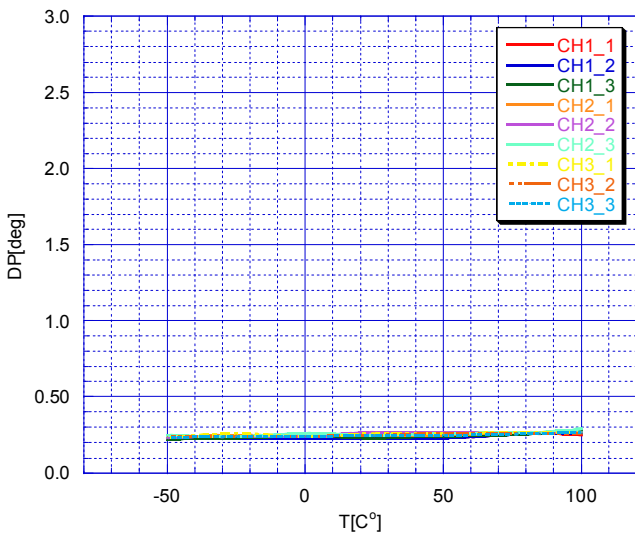
T vs SN



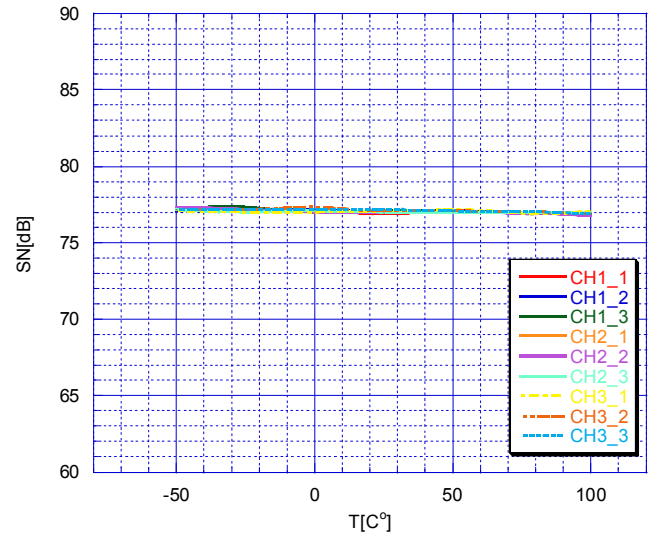
T vs DG



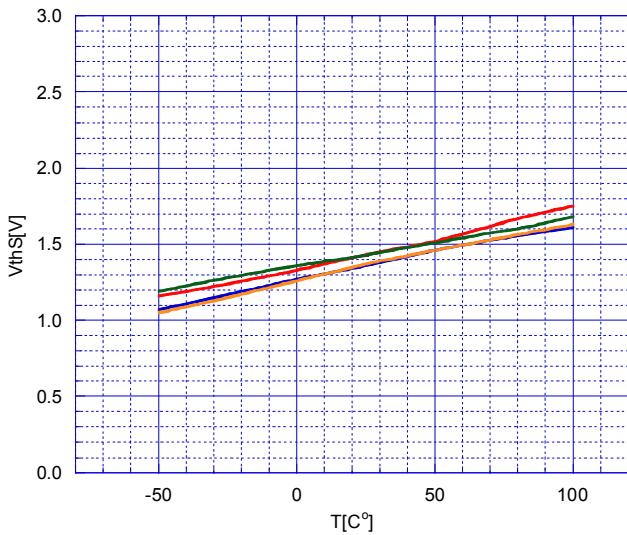
T vs DP



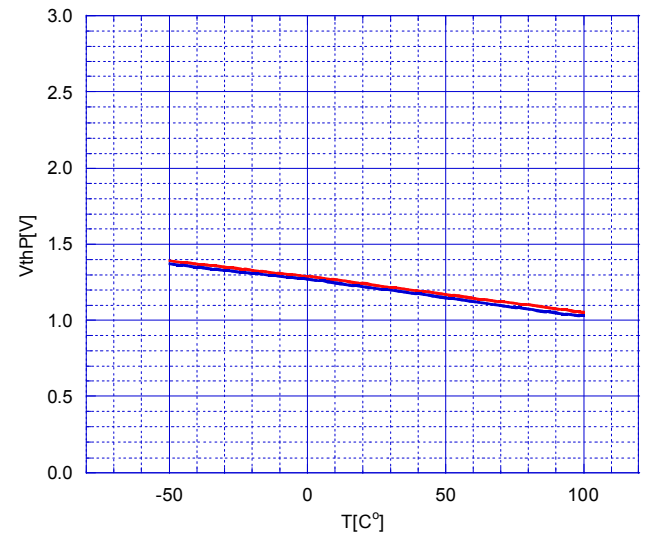
T vs SN



T vs VthS



T vs VthP





[CAUTION]
The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9